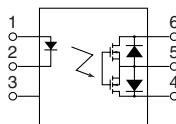
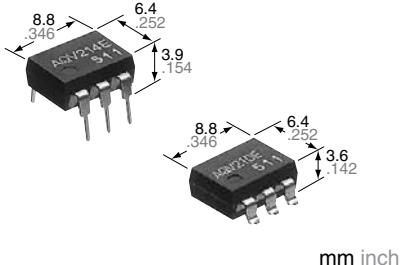


**General use and economy type.
DIP (1 Form A) 6-pin type.
Reinforced insulation
5,000V type.**

**GU-E PhotoMOS
(AQV210E, AQV210EH)**



FEATURES

1. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

2. Controlled with low-level input signals

3. Controls various types of loads such as relays, motors, lamps and solenoids.

4. Optical coupling for extremely high isolation

Unlike mechanical relays, the PhotoMOS relay combines LED and optoelectronic device to transfer signals using light for extremely high isolation.

5. Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side

6. Stable on-resistance

7. Low-level off state leakage current

8. Eliminates the need for a power supply to drive the power MOSFET

A power supply used to drive the power MOSFET is unnecessary because of the built-in optoelectronic device. This results in easy circuit design and small PC board area.

9. Low thermal electromotive force (Approx. 1 µV)

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computer

TYPES

Type	I/O isolation	Output rating*		Part No.				Packing quantity	
				Through hole terminal		Surface-mount terminal			
		Load voltage	Load current	Tube packing style		Tape and reel packing style			
AC/DC	Standard 1,500 V AC	350 V	130 mA	AQV210E	AQV210EA	AQV210EAX	AQV210EAZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.
		400 V	120 mA	AQV214E	AQV214EA	AQV214EAX	AQV214EAZ		
	Reinforced 5,000 V	350 V	130 mA	AQV210EH	AQV210EHA	AQV210EHAX	AQV210EHAZ		
		400 V	120 mA	AQV214EH	AQV214EHA	AQV214EHAX	AQV214EHAZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV210E(A)	AQV214E(A)	AQV210EH(A)	AQV214EH(A)	Remarks
Input	LED forward current	I _F		50 mA				
	LED reverse voltage	V _R		5 V				
	Peak forward current	I _{FP}		1 A				f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}		75 mW				
Output	Load voltage (peak AC)	V _L		350 V	400 V	350 V	400 V	
	Continuous load current	I _L	A	0.13 A	0.12 A	0.13 A	0.12 A	A connection: Peak AC, DC; B, C connection: DC
			B	0.15 A	0.13 A	0.15 A	0.13 A	
			C	0.17 A	0.15 A	0.17 A	0.15 A	
	Peak load current	I _{peak}		0.4 A	0.3 A	0.4 A	0.3 A	A connection: 100 ms (1 shot), V _L =DC
Power dissipation		P _{out}		500 mW				
Total power dissipation		P _T		550 mW				
I/O isolation voltage		V _{iso}		1,500 V AC		5,000 V AC		
Temperature limits	Operating	T _{opr}		-40°C to +85°C -40°F to +185°F				Non-condensing at low temp.
	Storage	T _{stg}		-40°C to +100°C -40°F to +212°F				

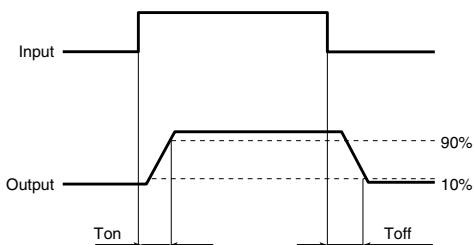
GU-E PhotoMOS (AQV21OE, AQV21OEH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV210E(A)	AQV214E(A)	AQV210EH(A)	AQV214EH(A)	Condition			
Input	LED operate current	Typical	I_{Fon}	—	1.1 mA			1.6 mA				
		Maximum			3 mA			$I_L = \text{Max.}$				
	LED turn off current	Minimum	I_{Foff}	—	0.3 mA			0.4 mA				
		Typical			1.0 mA			$I_L = \text{Max.}$				
Output	On resistance	Typical	R_{on}	A	23 Ω	30 Ω	23 Ω	30 Ω	$I_F = 5 \text{ mA}$			
		Maximum			35 Ω	50 Ω	35 Ω	50 Ω	$I_L = \text{Max.}$ Within 1 s on time			
		Typical	R_{on}	B	11.5 Ω	22.5 Ω	11.5 Ω	22.5 Ω	$I_F = 5 \text{ mA}$			
		Maximum			17.5 Ω	25 Ω	17.5 Ω	25 Ω	$I_L = \text{Max.}$ Within 1 s on time			
		Typical	R_{on}	C	6.0 Ω	11.3 Ω	6.0 Ω	11.3 Ω	$I_F = 5 \text{ mA}$			
		Maximum			8.8 Ω	12.5 Ω	8.8 Ω	12.5 Ω	$I_L = \text{Max.}$ Within 1 s on time			
Transfer characteristics	Output capacitance		Typical	C_{out}	A	45 pF						
	Off state leakage current		Maximum	—	—	1 μA						
	Switching speed	Turn on time*	Typical	T_{on}	—	0.5 ms	0.7 ms					
		Maximum	—	—	—	2.0 ms	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}^{**}$					
	I/O capacitance	Turn off time*	Typical	T_{off}	—	0.05 ms	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$					
		Maximum	—	—	—	1.0 ms	$I_L = \text{Max.}$					
	Initial I/O isolation resistance		Minimum	R_{iso}	—	0.8 pF						
			Maximum	—	—	1.5 pF						
	Initial I/O isolation resistance		Minimum	R_{iso}	—	1,000 MΩ						
*Turn on/Turn off time		For type of connection.										

*Turn on/Turn off time

For type of connection.



** Recommendable LED forward current

Standard type: $I_F = 5 \text{ mA}$

Reinforced type: $I_F = 5 \text{ to } 10 \text{ mA}$

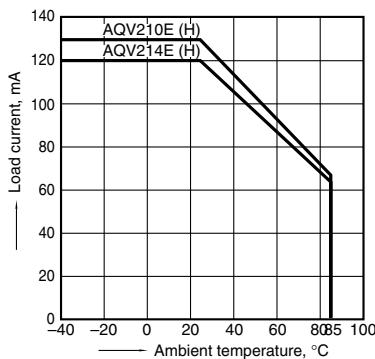
- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

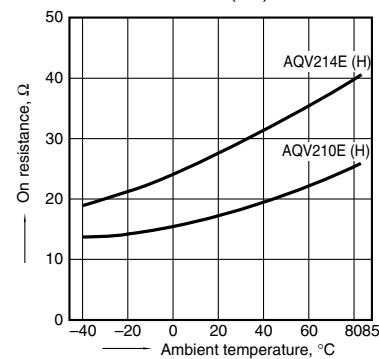
Allowable ambient temperature: -40°C to $+85^\circ\text{C}$
 -40°F to $+185^\circ\text{F}$

Type of connection:A



2. On-resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)

